

Features

- Operating voltage: 2.7V~5.2V
- External Crystal 32.768kHz oscillator
- 1/4 bias, 1/8 duty, frame frequency is 64Hz
- $\bullet \quad Max.\, 32{\times}8 \text{ patterns}, 8 \text{ commons}, 32 \text{ segments}\\$
- Built-in internal resistor type bias generator
- 3-wire serial interface
- 8 kinds of time base/WDT selection
- Time base or WDT overflow output
- Built-in LCD display RAM
- R/W address auto increment

(2kHz/4kHz)Power down command reduces power consumption

Two selectable buzzer frequencies

- Software configuration feature
- Data mode and Command mode instructions
- Three data accessing modes
- VLCD pin to adjust LCD operating voltage
- Cascade application

General Description

HT16220 is a peripheral device specially designed for I/O type μ C used to expand the display capability. The max. display segment of the device are 256 patterns (32×8). It also supports serial interface, buzzer sound, watchdog timer or time base timer functions. The HT16220 is a memory mapping and multi-function LCD controller. The software configuration feature of the HT16220 make it suitable for multiple LCD applications including LCD modules and display subsystems. Only three lines are required for the interface between the host controller and the HT16220. The HT162X series have many kinds of products that match various applications.

Selection Table

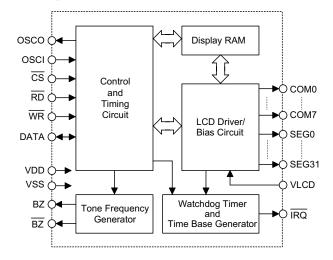
HT162X	HT1620	HT1621	HT1622	HT16220	HT1623	HT1625	HT1626	HT1627	HT16270
СОМ	4	4	8	8	8	8	16	16	16
SEG	32	32	32	32	48	64	48	64	64
Built-in Osc.		\checkmark	\checkmark		\checkmark	\checkmark	\checkmark	\checkmark	
Crystal Osc.	\checkmark	\checkmark		\checkmark	\checkmark	\checkmark	\checkmark		

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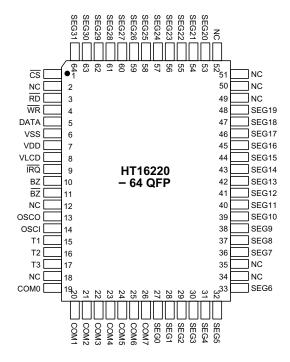


HT16220

Block Diagram



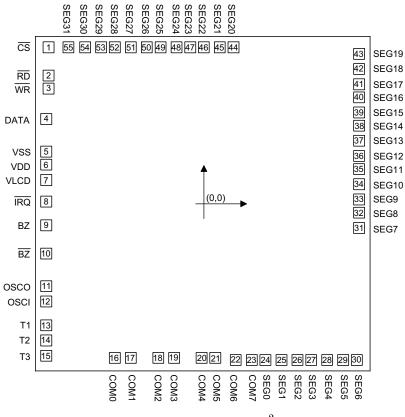
Pin Assignment



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Pad Assignment



Chip size: $151 \times 157 \text{ (mil)}^2$

* The IC substrate should be connected to VDD in the PCB layout artwork.

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Pad Coordinates

Unit: mil

Pad No.	X	Y	Pad No.	X	Y
1	-68.76	72.04	29	61.07	-72.33
2	-68.76	59.71	30	67.70	-72.33
3	-68.76	53.08	31	68.98	-10.41
4	-69.53	39.40	32	68.98	-3.78
5	-69.70	24.82	33	68.98	2.85
6	-69.70	18.19	34	68.98	9.48
7	-69.70	11.56	35	68.98	16.11
8	-69.70	1.36	36	68.98	22.74
9	-69.70	-10.28	37	68.98	29.37
10	-69.70	-23.55	38	68.98	36.00
11	-69.70	-38.93	39	68.98	42.63
12	-69.70	-45.56	40	68.98	49.26
13	-69.70	-56.53	41	68.98	55.89
14	-69.70	-63.83	42	68.98	62.52
15	-69.70	-70.46	43	68.98	69.15
16	-39.57	-71.57	44	13.85	72.04
17	-32.94	-71.57	45	7.22	72.04
18	-20.53	-71.57	46	0.60	72.04
19	-13.90	-71.57	47	-6.03	72.04
20	-1.49	-71.57	48	-12.66	72.04
21	5.14	-71.57	49	-19.30	72.04
22	14.66	-72.33	50	-25.92	72.04
23	21.29	-72.33	51	-32.56	72.04
24	27.92	-72.33	52	-39.19	72.04
25	34.55	-72.33	53	-45.81	72.04
26	41.18	-72.33	54	-52.44	72.04
27	47.81	-72.33	55	-59.08	72.04
28	54.44	-72.33			

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Pad Description

Pad No.	Pad Name	I/O	Description
1	CS	I	Chip selection input with pull-high resistor. When the \overline{CS} is logic high, the data and command read from or written to the HT16220 are disabled. The serial interface circuit is also reset But if the \overline{CS} is at logic low level and is input to the \overline{CS} pad, the data and command transmission between the host controller and the HT16220 are all enabled.
2	RD	I	READ clock input with pull-high resistor. Data in the RAM of the HT16220 are clocked out on the rising edge of the $\overline{\text{RD}}$ signal. The clocked out data will appear on the data line. The host controller can use the next falling edge to latch the clocked out data.
3	WR	Ι	WRITE clock input with pull-high resistor. Data on the DATA line are latched into the HT16220 on the rising edge of the $\overline{\rm WR}$ signal.
4	DATA	I/O	Serial data input/output with pull-high resistor
5	VSS	_	Negative power supply, ground
6	VDD	_	Positive power supply
7	VLCD	Ι	LCD operating voltage input pad.
8	ĪRQ	0	Time base or watchdog timer overflow flag, NMOS open drain output.
9, 10	BZ, \overline{BZ}	0	2kHz or 4kHz tone frequency output pair
11	OSCO	0	Crystal oscillator output pin
12	OSCI	Ι	Crystal oscillator input pin
13~15	T1~T3	Ι	Not connected
16~23	COM0~COM7	0	LCD common outputs
24~55	SEG0~SEG31	0	LCD segment outputs

Absolute Maximum Ratings

Supply Voltage	–0.3V to 5.5V
Input Voltage	$V_{\rm SS}$ –0.3V to V _{DD} +0.3V

Storage Temperature	50°C to 125°C
Operating Temperature	–25°C to 75°C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

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D.C. Characteristics

Ta=25°C
1a - 20 U

a 11			Test Conditions	М:	T		TT * 4
Symbol	Parameter	V _{DD}	Conditions	Min.	Тур.	Max.	Unit
V _{DD}	Operating Voltage	_		2.7	_	5.2	V
T	Operating Current		No load LCD ON		_	50	μΑ
I _{DD1}	Operating Current		Crystal oscillator		_	65	μΑ
T	Operating Current		No load/LCD OFF		_	20	μΑ
I_{DD2}			Crystal oscillator		_	30	μΑ
T	Standby Current		No load		1	8	μΑ
I _{STB}	Standby Current		Power down mode		2	16	μΑ
V	Input I ou Voltana			0	_	0.6	V
V_{IL}	Input Low Voltage	5V	DATA, \overline{WR} , \overline{CS} , \overline{RD}	0	_	1.0	V
V				2.4	_	3	V
V_{IH}	Input High Voltage	$\begin{array}{c c} \hline & & \\ \hline \\ \hline$		4.0	_	5	V
I		3V	V _{OL} =0.3V	0.9	1.8		mA
I _{OL1}	$BZ, \overline{BZ}, \overline{IRQ}$	5V	$V_{OL}=0.5V$	1.7	3	_	mA
T	BZ, \overline{BZ}	3V	V _{OH} =2.7V	-0.9	-1.8	_	mA
I _{OH1}	DL, DL	5V	$V_{OH}=4.5V$	-1.7	-3		mA
I		3V	$V_{OL}=0.3V$	200	450		μΑ
I _{OL1}	DATA	5V	$V_{OL}=0.5V$	250	500		μΑ
I	DATA	3V	V _{OH} =2.7V	-200	-450		μΑ
I _{OH1}	DATA	5V	$V_{OH}=4.5V$	-250	-500		μΑ
I	LOD Common Sinh Commont	3V	$V_{OL}=0.3V$	15	40		μΑ
I_{OL2}	LCD Common Sink Current	5V	$V_{OL}=0.5V$	100	200		μΑ
I	LCD Common Source Current	3V	$V_{OH}=2.7V$	-15	-30		μΑ
I_{OH2}	LCD Common Source Current	5V	$V_{OH}=4.5V$	-45	-90		μΑ
т	I CD Soment Sink Connect	3V	V _{OL} =0.3V	15	30	_	μΑ
I_{OL3}	L3 LCD Segment Sink Current		$V_{OL}=0.5V$	70	150		μΑ
Louis	I CD Sogmont Source Current	3V	V _{OH} =2.7V	-6	-13		μΑ
I _{OH3}	LCD Segment Source Current	5V	$V_{OH}=4.5V$	-20	-40		μΑ
Bru	Dull high Degister	3V		100	200	300	kΩ
R_{PH}	Pull-high Resistor	5V	DATA, $\overline{\mathrm{WR}}$, $\overline{\mathrm{CS}}$, $\overline{\mathrm{RD}}$	50	100	150	kΩ

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A.C. Characteristics

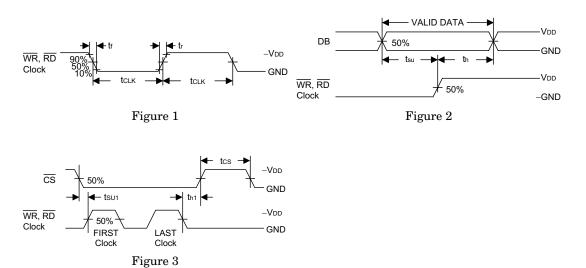
$Ta=25^{\circ}C$

G1 1	Dener	Test Conditions		N <i>T</i> .	m.	Max. 150 300 75 150	Unit
Symbol	Parameter	V _{DD}	Conditions	Min.	Тур.	max.	Unit
C		3V			32		kHz
f_{SYS}	System Clock	5V	Crystal oscillator		32	_	kHz
c		3V			64		Hz
f_{LCD}	LCD Frame Frequency	5V	Crystal oscillator		64	_	Hz
t _{COM}	LCD Common Period		n: Number of COM	_	n/f _{LCD}	_	sec
¢		3V			_	150	kHz
f_{CLK1}	Serial Data Clock (WR Pin)	5V	Duty cycle 50%		_	300	kHz
¢		3V			_	75	kHz
f_{CLK2}	Serial Data Clock (RD Pin)	5V	Duty cycle 50%		_	150	kHz
t _{CS}	Serial Interface Reset Pulse Width (Figure 3)		$\overline{\mathrm{CS}}$	_	250		ns
		3V Write m	Write mode	3.34	_		
+	WR, RD Input Pulse Width	31	Read mode	6.67	_		
t_{CLK}	(Figure 1)	5V	Write mode	1.67			
			Read mode	3.34			μs
t ta	Rise/Fall Time Serial Data	3V			190		ns
t _r , t _f	Clock (Figure 1)	5V			120		
	Setup Time for DATA to \overline{WR} ,	3V		_			ns
t_{SU}	RD Serial Data Clock (Figure 2)	5V			120		
	Hold Time for DATA to \overline{WR} ,	3V		_	120		ns
t _h	RD Serial Data Clock (Figure 2)	5V	5V			_	
torr	Setup Time for $\overline{\text{CS}}$ to $\overline{\text{WR}}$, $\overline{\text{RD}}$	3V			100		
t _{SU1}	Clock Width (Figure 3)	5V			100		ns
t _{h1}	Hold Time for $\overline{\text{CS}}$ to $\overline{\text{WR}}$, $\overline{\text{RD}}$	3V			100		ng
•h1	Clock Width (Figure 3)	5V			100		ns

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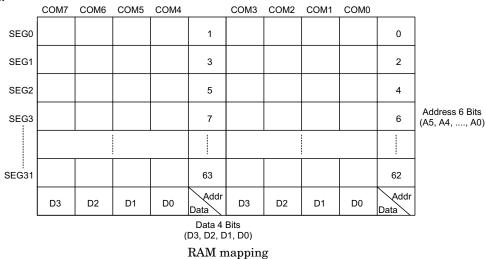
Functional Description

Display memory – RAM structure

The static display RAM is organized into 64×4 bits and stores the display data. The contents of the RAM are directly mapped to the contents of the LCD driver. Data in the RAM can be accessed by the READ, WRITE and READ-MODIFY-WRITE commands. The following is a mapping from the RAM to the LCD patterns.

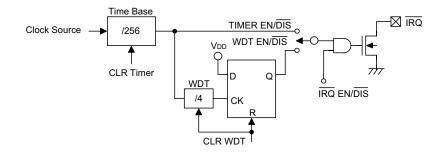
Time base and watchdog timer – WDT

The time base generator and WDT share the same divided (/256) counter. TIMER DIS/EN/CLR, WDT DIS/EN/CLR and \overline{IRQ} EN/DIS are independent from each other. Once the WDT time-out occurs, the \overline{IRQ} pin will stay at a logic low level until the CLR WDT or the \overline{IRQ} DIS commandisissued.



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Timer and WDT configurations

If an external clock is selected as the source of system frequency, the SYS DIS command turns out invalid and the power down mode fails to be carried out until the external clock source is removed.

Buzzer tone output

A simple tone generator is implemented in the HT16220. The tone generator can output a pair of differential driving signals on the BZ and $\overline{\text{BZ}}$ which are used to generate a single tone.

Command format

The HT16220 can be configured by the software setting. There are two mode commands to configure the HT16220 resource and to transfer the LCD display data.

The following are the data mode ID and the command mode ID:

Operation	Mode	ID
READ	Data	110
WRITE	Data	101
READ-MODIFY-WRITE	Data	101
COMMAND	Command	100

If successive commands have been issued, the command mode ID can be omitted. While the system is operating in the non-successive command or the non-successive address data mode, the $\overline{\text{CS}}$ pin should be set to "1" and the previous operation mode will be reset also. The $\overline{\text{CS}}$ pin returns to "0", a new operation mode ID should be issued first.

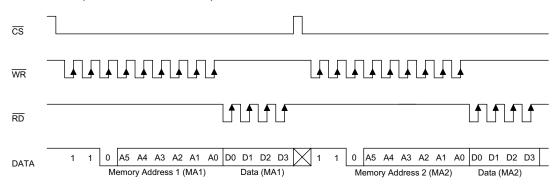
Name	Command Code	Function
TONE OFF	0000-1000-X	Turn-off tone output
TONE 4K	010X-XXXX-X	Turn-on tone output, tone frequency is 4kHz
TONE 2K	0110-XXXX-X	Turn-on tone output, tone frequency is 2kHz



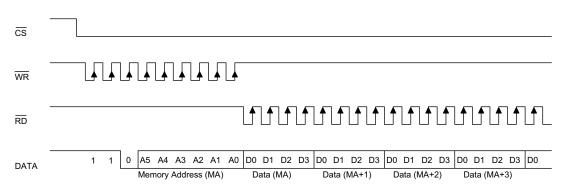


Timing Diagrams

READ mode (command code : 1 1 0)



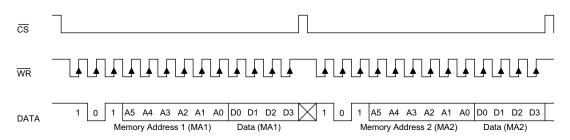
READ mode (successive address reading)



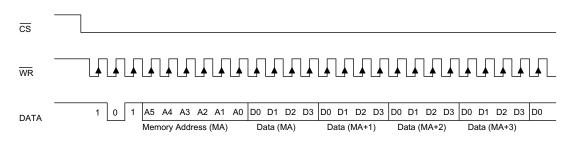
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WRITE mode (command code : 1 0 1)



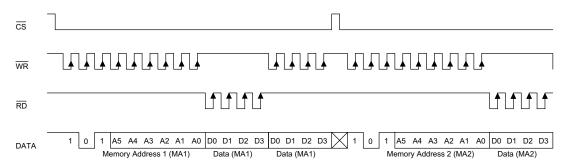
WRITE mode (successive address writing)



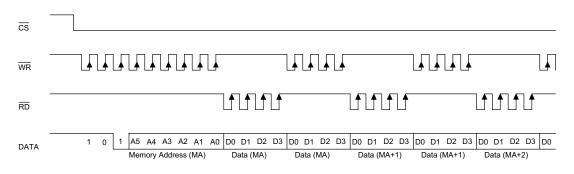
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READ-MODIFY-WRITE mode (command code : 1 0 1)



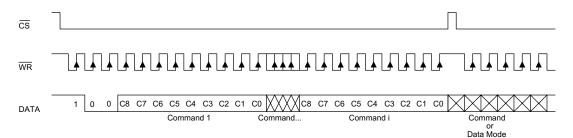
READ-MODIFY-WRITE mode (successive address accessing)



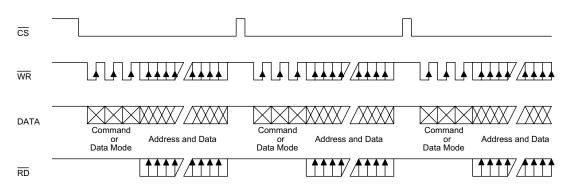
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Command mode (command code : 1 0 0)



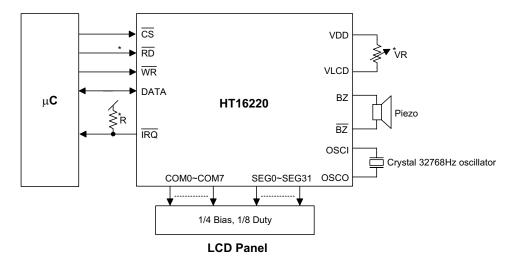
Mode (data and command mode)



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Application Circuits



*Note: The connection of \overline{IRQ} and \overline{RD} pin can be selected depending on the requirement of the $\mu C.$ The voltage applied to V_{LCD} pin must be lower than $V_{DD}.$ Adjust VR to fit LCD display, at $V_{DD}{=}5V, V_{LCD}{=}4V, VR{=}15k\Omega{\pm}20\%.$ Adjust R (external pull-high resistance) to fit user's time base clock.

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Command Summary

Name	ID	Command Code	D/C	Function	Def
READ	110	A5A4A3A2A1A0D0D1D2D3	D	Read data from the RAM	
WRITE	101	A5A4A3A2A1A0D0D1D2D3	D	Write data to the RAM	
READ- MODIFY- WRITE	101	A5A4A3A2A1A0D0D1D2D3	D	Read and Write data to the RAM	
SYS DIS	100 0000-0000-X		С	Turn off both system oscillator and LCD bias generator	Yes
SYS EN	100	0000-0001-X	С	Turn on system oscillator	
LCD OFF	100	0000-0010-X	С	Turn off LCD display	Yes
LCD ON	100	0000-0011-X	С	Turn on LCD display	
TIMER DIS	100	0000-0100-X	С	Disable time base output	Yes
WDT DIS	100	0000-0101-X	С	Disable WDT time-out flag output	Yes
TIMER EN	100	0000-0110-X	С	Enable time base output	
WDT EN	100	0000-0111-X	C	Enable WDT time-out flag output	
TONE OFF	100	0000-1000-X	C	Turn off tone outputs	Yes
CLR TIMER	100	0000-1101-X	C	Clear the contents of the time base generator	
CLR WDT	100	0000-1111-X	С	Clear the contents of the WDT stage	
TONE 4K	100	010X-XXXX-X	С	Tone frequency output: 4kHz	
TONE 2K	100	0110-XXXX-X	С	Tone frequency output: 2kHz	
$\overline{\text{IRQ}}$ DIS	100	100X-0XXX-X	С	Disable $\overline{\mathrm{IRQ}}$ output	Yes
$\overline{\text{IRQ}}$ EN	100	100X-1XXX-X	С	Enable $\overline{\mathrm{IRQ}}$ output	
F1	100	101X-0000-X	С	Time base clock output: 1Hz The WDT time-out flag after: 4s	
F2	100	101X-0001-X	С	Time base clock output: 2Hz The WDT time-out flag after: 2s	
F4	100	101X-0010-X	С	Time base clock output: 4Hz The WDT time-out flag after: 1s	
F8	100	101X-0011-X	С	Time base clock output: 8Hz The WDT time-out flag after: 1/2 s	
F16	100	101X-0100-X	С	Time base clock output: 16Hz The WDT time-out flag after: 1/4 s	

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Name	ID	Command Code	D/C	Function	Def.
F32	100	101X-0101-X	С	Time base clock output: 32Hz The WDT time-out flag after: 1/8 s	
F64	100	101X-0110-X	C	Time base clock output: 64Hz The WDT time-out flag after: 1/16 s	
F128	100	101X-0111-X	С	Time base clock output: 128Hz The WDT time-out flag after: 1/32 s	Yes
TEST	100	1110-0000-X	C	Test mode, user don't use.	
NORMAL	100	1110-0011-X	C	Normal mode	Yes

Note: X : Don't care

A5~A0 : RAM address

D3~D0 : RAM data

D/C : Data/Command mode

Def. : Power on reset default

All the bold forms, namely **1 1 0, 1 0 1**, and **1 0 0**, are mode commands. Of these, **1 0 0** indicates the command mode ID. If successive commands have been issued, the command mode ID except for the first command will be omitted. The source of the tone frequency and of the time base/WDT clock frequency can be derived from a 32.768kHz crystal oscillator or an external 32kHz clock. Calculation of the frequency is based on the system frequency sources as stated above. It is recommended that the host controller should initialize the HT16220 after power on reset, for power on reset may fail, which in turn leads to malfunctioning of the HT16220.

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